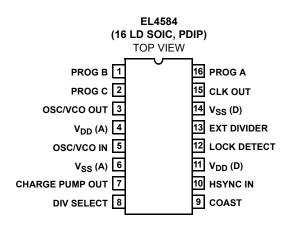
Pinout





Absolute Maximum Ratings (T_A = +25°C)

V _{CC} Supply	7V
Operating Junction Temperature	+125°C
Storage Temperature65°C to	+150°C
Power Dissipation	400mW

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
I _{DD}	V _{DD} = 5V (Note 4)		2	4	mA
V _{IL} Input Low Voltage				1.5	V
V _{IH} Input High Voltage		3.5			V
IIL Input Low Current	All inputs except COAST, V _{IN} = 1.5V	-100			nA
I _{IH} Input High Current	All inputs except COAST, V _{IN} = 3.5V			100	nA
IIL Input Low Current	COAST pin, V _{IN} = 1.5V	-100	-60		μA
I _{IH} Input High Current	COAST pin, V _{IN} = 3.5V		60	100	μA
V _{OL} Output Low Voltage	Lock Det, I _{OL} = 1.6mA			0.4	V
V _{OH} Output High Voltage	Lock Det, I _{OH} = -1.6mA	2.4			V
V _{OL} Output Low Voltage	CLK, I _{OL} = 3.2mA			0.4	V
V _{OH} Output High Voltage	CLK, I _{OH} = -3.2mA	2.4			V
V _{OL} Output Low Voltage	OSC Out, I _{OL} = 200µA			0.4	V
V _{OH} Output High Voltage	OSC Out, I _{OH} = -200µA	2.4			V
I _{OL} Output Low Current	Filter Out, V _{OUT} = 2.5V	200	300		μA
I _{OH} Output High Current	Filter Out, V _{OUT} = 2.5V		-300	-200	μA
I _{OL} /I _{OH} Current Ratio	Filter Out, V _{OUT} = 2.5V	1.05	1.0	0.95	
I _{LEAK} Filter Out	Coast Mode, V _{DD} > V _{OUT} > 0V	-100	±1	100	nA

DC Electrical Specifications V_{DD} = 5V, T_A = +25°C unless otherwise noted.

NOTE:

4. All inputs to 0V, COAST floating.

AC Electrical Specifications V_{DD} = 5V, T_A = +25°C unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
VCO Gain @ 20MHz	Test circuit 1		15.5		dB
H _{SYNC} S/N Ratio	V _{DD} = 5V (Note 5)	35			dB
Jitter	VCXO oscillator		1		ns
Jitter	LC oscillator (Typ)		10		ns

NOTE:

5. Noisy video signal input to EL4583, ${\rm H}_{\rm SYNC}$ input to EL4584. Test for positive signal lock.



Pin Descriptions

PIN NUMBER	PIN NAME	FUNCTION
1, 2, 16	PROG B, PROG C, PROG A	Digital inputs to select ÷ N value for internal counter. See Table 2 for values.
3	OSC/VCO OUT	Output of internal inverter/oscillator. Connect to external crystal or LC tank VCO circuit.
4	VDD (A)	Analog positive supply for oscillator, PLL circuits.
5	OSC/VCO IN	Input from external VCO.
6	VSS (A)	Analog ground for oscillator, PLL circuits.
7	CHARGE PUMP OUT	Connect to loop filter. If the H _{SYNC} phase is leading or H _{SYNC} frequency > CLK \div N, current is pumped into the filter capacitor to increase VCO frequency. If H _{SYNC} phase is lagging or frequency < CLK \div N, current is pumped out of the filter capacitor to decrease VCO frequency. During coast mode or when locked, charge pump goes to a high impedance state.
8	DIV SELECT	Divide select input. When high, the internal divider is enabled and EXT DIV becomes a test pin, outputting CLK ÷ N. When low, the internal divider is disabled and EXT DIV is an input from an external ÷ N.
9	COAST	Tri-state logic input. Low (<1/3*V _{CC}) = normal mode, Hi Z (or 1/3 to $2/3*V_{CC}$) = fast lock mode, High (>2/3*V _{CC}) = coast mode.
10	HSYNC IN	Horizontal sync pulse (CMOS level) input.
11	VDD (D)	Positive supply for digital, I/O circuits.
12	LOCK DETECT	Lock Detect output. Low level when PLL is locked. Pulses high when out of lock.
13	EXT DIVIDER	External Divide input when DIV SEL is low, internal +N output when DIV SEL is high.
14	VSS (D)	Ground for digital, I/O circuits.
15	CLK OUT	Buffered output of the VCO.

TABLE 2. VCO DIVISORS

PROG A (PIN 16)	PROG B (PIN 1)	PROG C (PIN 2)	DIV VALUE (N)
0	0	0	851
0	0	1	864
0	1	0	944
0	1	1	1135
1	0	0	682
1	0	1	858
1	1	0	780
1	1	1	910

Timing Diagrams

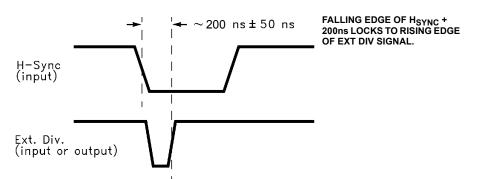
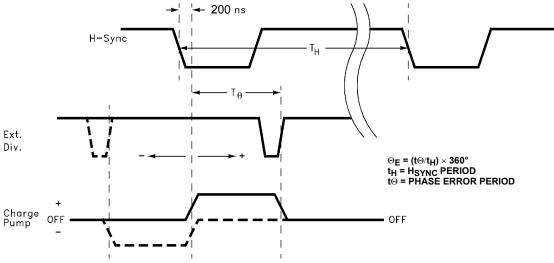


FIGURE 1. PLL LOCKED CONDITION (PHASE ERROR = 0)





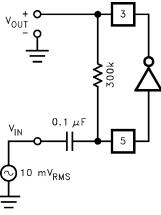
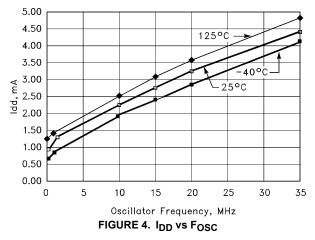


FIGURE 3. TEST CIRCUIT 1



Typical Performance Curves



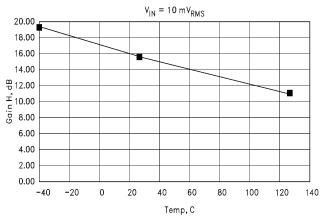


FIGURE 5. EL4584 OSC GAIN @ 20MHz vs TEMPERATURE

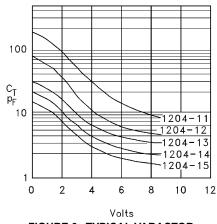
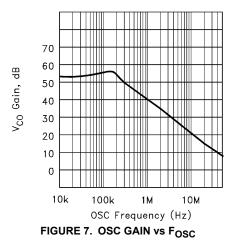


FIGURE 6. TYPICAL VARACTOR



JEDEC JESD51-3 LOW EFFECTIVE THERMAL CONDUCTIVITY TEST BOARD

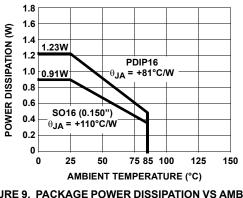
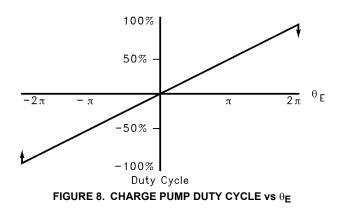
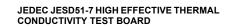


FIGURE 9. PACKAGE POWER DISSIPATION VS AMBIENT TEMPERATURE





Typical Performance Curves (Continued)



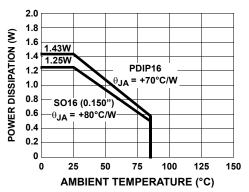
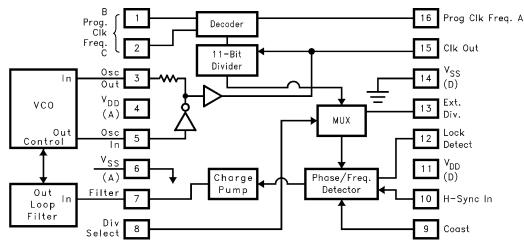


FIGURE 10. PACKAGE POWER DISSIPATION VS AMBIENT TEMPERATURE

Block Diagram



Description Of Operation

The horizontal sync signal (CMOS level, falling leading edge) is input to H_{SYNC} input (pin 10). This signal is delayed about 200ns, the falling edge of which becomes the reference to which the clock output will be locked (see "Timing Diagrams" on page 5 and page 6). The clock is generated by the signal on pin 5, OSC IN. There are 2 general types of VCO that can be used with the EL4584; LC and crystal controlled. Additionally, each type can be either built-up using discrete components, including a varactor as the frequency controlling element, or complete, self contained modules can be purchased with everything inside a metal can. The modules are very forgiving of PCB layout, but cost more than discrete solutions. The VCO or VCXO is used to generate the clock. An LC tank resonator has greater "pull" than a crystal controlled circuit, but will also be more likely to drift over time, and thus will generate more jitter. The "pullability" of the circuit refers to the ability to "pull" the frequency of oscillation away from its center frequency by modulating the voltage on the control pin of a VCO module or varactor, and is a function of the slope and range

of the capacitance-voltage curve of the varactor or VCO module used. The VCO signal is sent to a divide by N counter, and to the CLK OUT pin. The divisor N is determined by the state of pins 1, 2 and 16 and is described in Table 2. The divided signal is sent, along with the delayed H_{SYNC} input, to the phase/frequency detector, which compares the two signals for phase and frequency differences. Any phase difference is converted to a current at the charge pump output FILTER (pin 7). A VCO with positive frequency deviation with control voltage must be used. Varactors have negative capacitance slope with voltage, resulting in positive frequency deviation with control voltage for the oscillators in Figures 12 and 13.

vco

The VCO should be tuned so its frequency of oscillation is very close to the required clock output frequency when the voltage on the varactor is 2.5V. VCXO and VCO modules are already tuned to the desired frequency, so this step is not necessary if using one of these units. The range of the charge pump output (pin 7) is 0V to 5V and it can source or sink a maximum of about 300μ A, so all frequency control



must be accomplished with variable capacitance from the varactor within this range. Crystal oscillators are more stable than LC oscillators, which translates into lower jitter, but LC oscillators can be pulled from their mid-point values further, resulting in a greater capture and locking range. If the incoming horizontal sync signal is known to be very stable, then a crystal oscillator circuit can be used. If the HSYNC signal experiences frequency variations of greater than about 300ppm, an LC oscillator should be considered, as crystal oscillators are very difficult to pull this far. When H_{SYNC} input frequency is greater than CLK frequency ÷ N, charge pump output (pin 7) sources current into the filter capacitor, increasing the voltage across the varactor, which lowers its capacitance, thus tending to increase VCO frequency. Conversely, filter output pulls current from the filter capacitor when H_{SYNC} frequency is less than CLK ÷ N, forcing the VCO frequency lower.

Loop Filter

The loop filter controls how fast the VCO will respond to a change in filter output stimulus. Its components should be chosen so that fast lock can be achieved, yet with a minimum of VCO "hunting", preferably in one to two oscillations of charge pump output, assuming the VCO frequency starts within capture range. If the filter is under-damped, the VCO will over and under-shoot the desired operating point many times before a stable lock takes place. It is possible to under-damp the filter so much that the loop itself oscillates, and VCO lock is never achieved. If the filter is over-damped, the VCO response time will be excessive and many cycles will be required for a lock condition. Over-damping is also characterized by an easily unlocked system because the filter can't respond fast enough to perturbations in VCO frequency. A severely over-damped system will seem to endlessly oscillate, like a very large mass at the end of a long pendulum. Due to parasitic effects of PCB traces and component variables, it will take some trial and error experimentation to determine the best values to use for any given situation. Use the component tables as a starting point, but be aware that deviation from these values is not out of the ordinary.

External Divide

DIV SELECT (pin 8) controls the use of the internal divider. When high, the internal divider is enabled and EXT DIVIDER (pin 13) outputs the CLK out divided by N. This is the signal to which the horizontal sync input will lock. When divide select is low, the internal divider output is disabled, and the external divide becomes an input from an external divider, so that a divisor other than one of the 8 pre-programmed internal divisors can be used.

Normal Mode

Normal mode is enabled by pulling COAST (pin 9) low (below $1/3^*V_{CC}$). If H_{SYNC} and CLK ÷ N have any phase or frequency difference, an error signal is generated and sent to the charge pump. The charge pump will either force current into or out of the filter capacitor in an attempt to modulate the

VCO frequency. Modulation will continue until the phase and frequency of CLK \div N exactly match the H_{SYNC} input. When the phase and frequency match (with some offset in phase that is a function of the VCO characteristics), the error signal goes to zero, lock detect no longer pulses high, and the charge pump enters a high impedance state. The clock is now locked to the H_{SYNC} input. As long as phase and frequency differences remain small, the PLL can adjust the VCO to remain locked and lock detect remains low.

Fast Lock Mode

Fast Lock mode is enabled by either allowing coast to float, or pulling it to mid supply (between 1/3 and $2/3^*V_{CC}$). In this mode, lock is achieved much faster than in normal mode, but the clock divisor is modified on the fly to achieve this. If the phase detector detects an error of enough magnitude, the clock is either inhibited or reset to attempt a "fast" lock of the signals.

Forcing the clock to be synchronized to the H_{SYNC} input this way allows a lock in approximately 2 H-cycles, but the clock spacing will not be regular during this time. Once the near lock condition is attained, charge pump output should be very close to its lock-on value and placing the device into normal mode should result in a normal lock very quickly. Fast Lock mode is intended to be used where H_{SYNC} becomes irregular, until a stable signal is again obtained.

Coast Mode

Coast mode is enabled by pulling the COAST (pin 9) high (above $2/3^*V_{CC}$). In coast mode, the internal phase detector is disabled and filter out remains in high impedance mode to keep filter out voltage and VCO frequency as constant as possible. VCO frequency will drift as charge leaks from the filter capacitor, and the voltage changes the VCO operating point. Coast mode is intended to be used when noise or signal degradation results in loss of horizontal sync for many cycles. The phase detector will not attempt to adjust to the resultant loss of signal so that when horizontal sync returns, sync lock can be re-established quickly. However, if much VCO drift has occurred, it may take as long to re-lock as when restarting.

Lock Detect

LOCK DETECT (pin 12) will go low when lock is established. Any DC current path from charge pump out will skew EXT DIVIDER relative to HSYNC IN, tending to offset or add to the 200ns internal delay, depending on which way the extra current is flowing. This offset is called static phase error, and is always present in any PLL system. If, when the part stabilizes in a locked mode, lock detect is not low, adding or subtracting from the loop filter series resistor R₂ will change this static phase error to allow LDET to go low while in lock. The goal is to put the rising edge of EXT DIVIDER in sync with the falling edge of H_{SYNC} + 200ns (see "Timing Diagrams" on page 5 and page 5). Increasing R₂ decreases phase error, while decreasing R₂ increases phase error (phase error is positive when EXT DIVIDER lags HSYNC.)



The resistance needed will depend on VCO design or VCXO module selection.

Applications Information

Choosing External Components

- To choose LC VCO components, first pick the desired operating frequency. For our example, we will use 14.31818MHz, with an H_{SYNC} frequency of 15.734kHz.
- 2. Choose a reasonable inductor value (10μH to 20μH works well). We choose 15μH.
- 3. Calculate C_T needed to produce F_{OSC} , as shown in Equations 1 and 2.

$$F_{OSC} = \frac{1}{2\pi \sqrt{LC_T}}$$
(EQ. 1)

$$C_{T} = \frac{1}{4\pi^{2}F^{2}L} = \frac{1}{4\pi^{2}(14.318e6)^{2}(15e-6)} = 8.2pF$$
 (EQ. 2)

- From the varactor data sheet find C_V @ 2.5V, the desired lock voltage. C_V = 23pF for our SMV1204-12, for example.
- 5. C₂ should be about $10C_V$, so we choose C₂ = 220pF for our example.
- 6. Calculate C1 using Equations 3 and 4. Since:

$$C_{T} = \frac{C_{1}C_{2}C_{V}}{(C_{1}C_{2}) + (C_{1}C_{V}) + (C_{2}C_{V})'}$$
(EQ. 3)

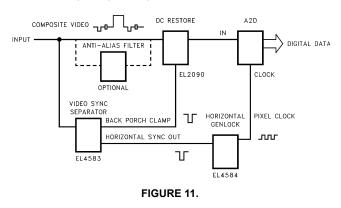
then:

$$C_{1} = \frac{C_{2}C_{T}C_{V}}{(C_{2}C_{V}) - (C_{2}C_{T}) - (C_{T}C_{V})'}$$
(EQ. 4)

For our example, $C_1 = 14pF$ (a trim capacitor may be used for fine tuning). Examples for each frequency using the internal divider follow.

Typical Application

Horizontal genlock provides clock for an analog to digital converter, digitizing analog video.



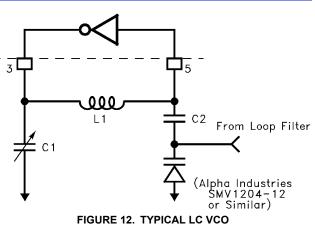


FIGURE 12. ITPICAL LC VCU

TABLE 3. LC VCO COMPONENT VALUES (APPROXIMATE) (NOTE)

FREQUENCY (MHZ)	L ₁ (μΗ)	С ₁ (рF)	С ₂ (рF)
13.301	15	18	220
13.5	15	17	220
14.75	12	18	220
17.734	12	10	220
10.738	22	20	220
12.273	18	17	220
14.318	15	14	220

NOTE: Use shielded inductors for optimum performance.

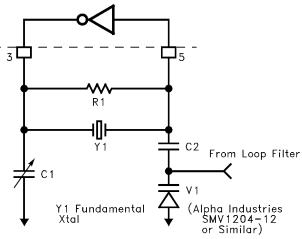


FIGURE 13. TYPICAL XTAL VCO

TABLE 4. XTAL VCO COMPONENT VALUES (APPROXIMATE)

FREQUENCY (MHz)	R₁ (kΩ)	С ₁ (рF)	С ₂ (µF)
13.301	300	15	0.001
13.5	300	15	0.001
14.75	300	15	0.001



FREQUENCY (MHz)	R 1 (kΩ)	С ₁ (рF)	C ₂ (μF)
17.734	300	15	0.001
10.738	300	15	0.001
12.273	300	15	0.001
14.318	300	15	0.001

TABLE 4. XTAL VCO COMPONENT VALUES (APPROXIMATE) (Continued)

The above oscillators are arranged as Colpitts oscillators, and the structure is redrawn here to emphasize the split capacitance used in a Colpitts oscillator. It should be noted that this oscillator configuration is just one of literally hundreds possible, and the configuration shown here does not necessarily represent the best solution for all applications. Crystal manufacturers are very informative sources on the design and use of oscillators in a wide variety of applications, and the reader is encouraged to become familiar with them.

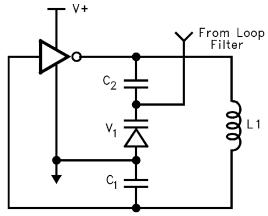


FIGURE 14. COLPITTS OSCILLATOR

C₁ is to adjust the center frequency, C₂ DC isolates the control from the oscillator, and V1 is the primary control device. C₂ should be much larger than C_V so that V₁ has maximum modulation capability. The frequency of oscillation is given by Equations 5 and 6:

$$F = \frac{1}{12\pi \sqrt{LC_T}}$$
(EQ. 5)

$$C_{T} = \frac{C_{1}C_{2}C_{V}}{(C_{1}C_{2}) + (C_{1}C_{V}) + (C_{2}C_{V})}$$
(EQ. 6)

Choosing Loop Filter Components

The PLL, VCO, and loop filter can be represented in Figure 15:

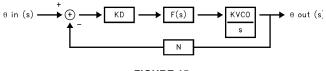


FIGURE 15.

Where:

 K_d = phase detector gain in A/rad

F(s) = loop filter impedance in V/A

K_{VCO} = VCO gain in rad/s/V

N = internal or external divisor

It can be shown that for the loop filter shown in Equation 7:

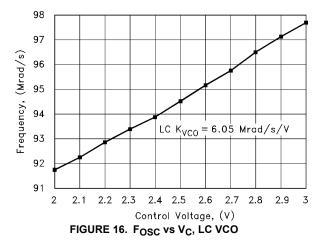
$$C_3 = \frac{K_d K_{VCO}}{N\omega_n^2}, C_4 = \frac{C_3}{10}, R_3 = \frac{2N\xi\omega_n}{K_d K_{VCO}}$$
 (EQ. 7)

Where ϖ_n = loop filter bandwidth, and ζ = loop filter damping factor.

- 1. $K_d = 300 \mu A/2\pi rad = 4.77e-5A/rad$ for the EL4584.
- The loop bandwidth should be about H_{SYNC} frequency/20, and the damping ratio should be 1 for optimum performance. For our example, [∞]_n = 15.734kHz/20 = 787Hz≈5000rad/S.
- 3. N = 910 from Table 2.

$$N = \frac{VCOfrequency}{H-SYNCfrequency} = \frac{14.31818M}{15.73426k} = 910$$
 (EQ. 8)

4. K_{VCO} represents how much the VCO frequency changes for each volt applied at the control pin. It is assumed (but probably is not) linear about the lock point (2.5V). Its value depends on the VCO configuration and the varactor transfer function $C_V = F(V_C)$, where V_C is the reverse bias control voltage, and C_V is varactor capacitance. Since $F(V_C)$ is nonlinear, it is probably best to build the VCO and measure K_{VCO} about 2.5V. The results of one such measurement are shown in the following. The slope of the curve is determined by linear regression techniques and equals K_{VCO} . For our example, $K_{VCO} = 6.05$ Mrad/S/V.



- 5. Now we can solve for C3, C4, and R3. We choose R3 = $30k\Omega$ for convenience.
- Notice R₂ has little effect on the loop filter design. R₂ should be large, around 100k, and can be adjusted to compensate for any static phase error tθ at lock, but if made too large, will slow loop response. If R₂ is made

smaller, t θ (see "Timing Diagrams" on page 5) increases, and if R₂ increases, t θ decreases. For LDET to be low at lock, $|t\theta| < 50$ ns. C₄ is used mainly to attenuate high frequency noise from the charge pump.

$$C_3 = \frac{K_d K_{VCO}}{N\omega_n^2} = \frac{(4.77e - 5)(6.05e6)}{(910)(5000)^2} = 0.01 \mu F$$
(EQ. 9)

$$C_4 = \frac{C_3}{10} = 0.0001 \,\mu\text{F}$$
 (EQ. 10)

$$\mathsf{R}_3 = \frac{2\mathsf{N}\zeta \omega_n}{\mathsf{K}_d\mathsf{K}_{VCO}} = \frac{(2)(910)(1)(5000)}{(4.77e-5)(6.05e6)} = 31.5 \mathsf{k}\Omega \tag{EQ. 11}$$

Lock Time

Let = R₃C₃. As t increases, damping increases, but so does lock time. Decreasing t decreases damping and speeds up loop response, but increases overshoot and thus increases the number of hunting oscillations before lock. Critical damping (ζ = 1) occurs at minimum lock time. Because decreased damping also decreases loop stability, it is sometimes desirable to design slightly overdamped (ζ > 1), trading lock time for increased stability.

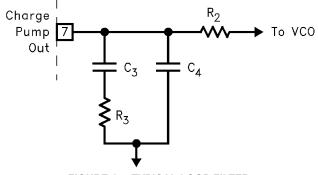


FIGURE 17. TYPICAL LOOP FILTER

FREQUENCY (MHz)	R₂ (kΩ)	R 3 (kΩ)	С ₃ (µF)	С ₄ (µF)
13.301	100	30	0.01	0.001
13.5	100	30	0.01	0.001
14.75	100	33	0.01	0.001
17.734	100	39	0.01	0.001
10.738	100	22	0.01	0.001
12.273	100	27	0.01	0.001
14.318	100	30	0.01	0.001

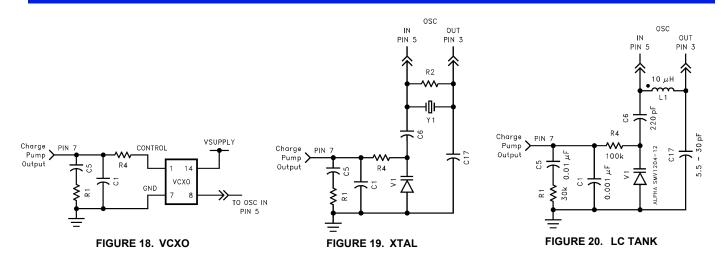
TABLE 6. XTAL LOOP FILTER COMPONENTS (APPROXIMATE)

FREQUENCY (MHz)	R₂ (kΩ)	R 3 (ΜΩ)	С ₃ (рF)	С ₄ (рF)
13.301	100	4.3	68	6.8
13.5	100	4.3	68	6.8
14.75	100	4.3	68	6.8
17.734	100	4.3	68	6.8
10.738	100	4.3	68	6.8
12.273	100	4.3	68	6.8
14.318	100	4.3	68	6.8

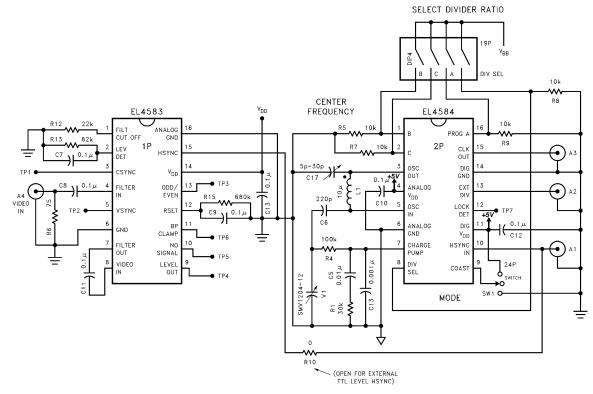
PCB Layout Considerations

It is highly recommended that power and ground planes be used in layout. The oscillator and filter sections constitute a feedback loop and thus care must be taken to avoid any feedback signal influencing the oscillator except at the control input. The entire oscillator/filter section should be surrounded by copper ground to prevent unwanted influences from nearby signals. Use separate paths for analog and digital supplies, keeping the analog (oscillator section) as short and free from spurious signals as possible. Careful attention must be paid to correct bypassing. Keep lead lengths short and place bypass capacitors as close to the supply pins as possible. If laying out a PCB to use discrete components for the VCO section, care must be taken to avoid parasitic capacitance at the OSC pins 3 and 5, and FILTER out (pin 7). Remove ground and power plane copper above and below these traces to avoid making a capacitive connection to them. It is also recommended to enclose the oscillator section within a shielded cage to reduce external influences on the VCO, as they tend to be very sensitive to "handwaving" influences, the LC variety being more sensitive than crystal controlled oscillators. In general, the higher the operating frequency, the more important these considerations are. Self contained VCXO or VCO modules are already mounted in a shielding cage and therefore do not require as much consideration in layout. Many crystal manufacturers publish informative literature regarding use and layout of oscillators which should be helpful.

The VCO and loop filter section of the EL4583, EL4584, EL4585 demo board can be implemented in Figures 18, 19 and 20.



Demo Board





Component Sources

Inductors

Dale Electronics

 E. Highway 50
 PO Box 180
 Yankton, SD 57078-0180
 (605) 665-9301

Crystals, VCXO, VCO Modules

- Connor-Winfield 2111 Comprehensive Drive Aurora, IL 60606 (708) 851-4722
- Piezo Systems

 100 K Street
 PO Box 619
 Carlisle, PA 17013
 (717) 249-2151
- Reeves-Hoffman 400 West North Street Carlisle, PA 17013 (717) 243-5929

- SaRonix
 151 Laura Lane
 Palo Alto, CA 94043
 (415) 856-6900
- Standard Crystal 9940 Baldwin Place El Monte, CA 91731 (818) 443-2121

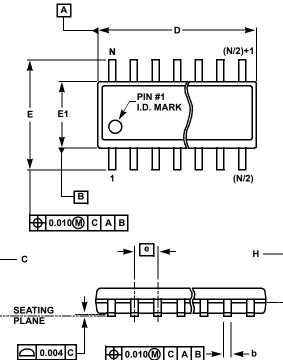
Varactors

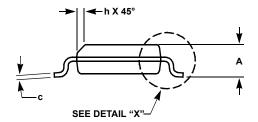
- Sky Works Solutions Inc. 20 Sylvan Road Woburn, MA 01801 (781) 376-3000 www.skyworksinc.com
- Motorola Semiconductor Products 2100 E. Elliot Tempe, AZ 85284 (602) 244-6900

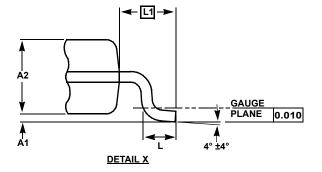
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MDP0027

SMALL OUTLINE PACKAGE FAMILY (SO)

		INCHES							
SYMBOL	SO-8	SO-14	SO16 (0.150")	SO16 (0.300") (SOL-16)	SO20 (SOL-20)	SO24 (SOL-24)	SO28 (SOL-28)	TOLERANCE	NOTES
А	0.068	0.068	0.068	0.104	0.104	0.104	0.104	MAX	-
A1	0.006	0.006	0.006	0.007	0.007	0.007	0.007	±0.003	-
A2	0.057	0.057	0.057	0.092	0.092	0.092	0.092	±0.002	-
b	0.017	0.017	0.017	0.017	0.017	0.017	0.017	±0.003	-
С	0.009	0.009	0.009	0.011	0.011	0.011	0.011	±0.001	-
D	0.193	0.341	0.390	0.406	0.504	0.606	0.704	±0.004	1, 3
Е	0.236	0.236	0.236	0.406	0.406	0.406	0.406	±0.008	-
E1	0.154	0.154	0.154	0.295	0.295	0.295	0.295	±0.004	2, 3
е	0.050	0.050	0.050	0.050	0.050	0.050	0.050	Basic	-
L	0.025	0.025	0.025	0.030	0.030	0.030	0.030	±0.009	-
L1	0.041	0.041	0.041	0.056	0.056	0.056	0.056	Basic	-
h	0.013	0.013	0.013	0.020	0.020	0.020	0.020	Reference	-
Ν	8	14	16	16	20	24	28	Reference	-

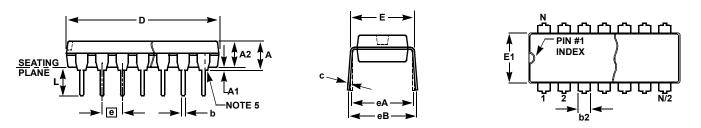
Rev. M 2/07

NOTES:

- 1. Plastic or metal protrusions of 0.006" maximum per side are not included.
- 2. Plastic interlead protrusions of 0.010" maximum per side are not included.
- 3. Dimensions "D" and "E1" are measured at Datum Plane "H".
- 4. Dimensioning and tolerancing per ASME Y14.5M-1994



Plastic Dual-In-Line Packages (PDIP)



MDP0031 PLASTIC DUAL-IN-LINE PACKAGE

SYMBOL	INCHES						
	PDIP8	PDIP14	PDIP16	PDIP18	PDIP20	TOLERANCE	NOTES
А	0.210	0.210	0.210	0.210	0.210	MAX	
A1	0.015	0.015	0.015	0.015	0.015	MIN	
A2	0.130	0.130	0.130	0.130	0.130	±0.005	
b	0.018	0.018	0.018	0.018	0.018	±0.002	
b2	0.060	0.060	0.060	0.060	0.060	+0.010/-0.015	
С	0.010	0.010	0.010	0.010	0.010	+0.004/-0.002	
D	0.375	0.750	0.750	0.890	1.020	±0.010	1
E	0.310	0.310	0.310	0.310	0.310	+0.015/-0.010	
E1	0.250	0.250	0.250	0.250	0.250	±0.005	2
е	0.100	0.100	0.100	0.100	0.100	Basic	
eA	0.300	0.300	0.300	0.300	0.300	Basic	
eB	0.345	0.345	0.345	0.345	0.345	±0.025	
L	0.125	0.125	0.125	0.125	0.125	±0.010	
Ν	8	14	16	18	20	Reference	

NOTES:

- 1. Plastic or metal protrusions of 0.010" maximum per side are not included.
- 2. Plastic interlead protrusions of 0.010" maximum per side are not included.
- 3. Dimensions E and eA are measured with the leads constrained perpendicular to the seating plane.
- 4. Dimension eB is measured with the lead tips unconstrained.
- 5. 8 and 16 lead packages have half end-leads as shown.

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